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Test Data Document:

81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

General Description:

A gallium arsenide diode is optically coupled to a silicon npn phototransistor; led maximum ratings consist of 2v vr; 40ma if; 1a ip; 25 degrees c ta; phototransistor maximum ratings consist of 35v vceo; 35v vcbo; 4v vebo; 50ma ic; 300mw pt; 0.155 in. To 0.185 in. Maximum lg; 0.335 in. To 0.370 in. Maximum dia; 6 lead type terminals

Specification Data:

81349-mil-prf-19500/486 government specification

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fig:

A23900

Mil-std (military Standard):

Mil-prf-19500 spec.